

**IN THE CLAIMS**

Please amend the claims to read as indicated herein.

1. (currently amended) An automated method for designing an integrated circuit (IC) design-specific cell, said method comprising the steps of:  
receiving a design specification for electrical behavior or transistor-level characteristics of said design-specific cell;  
mapping said design specification to a transistor-level representation of said design-specific cell, ~~said mapping based on said design specification; and;~~  
evaluating said transistor-level representation of said design-specific cell for meeting said design specification; and  
altering said transistor-level representation of said design-specific cell to meet said design specification.
2. (previously presented) The method of claim 1, wherein said step of evaluating comprises evaluating said transistor-level representation of said design-specific cell based on a specific design context in which said design-specific cell is to be used.
3. (original) The method of claim 1, wherein said step of receiving comprises receiving a description of said design-specific cell.
4. (original) The method of claim 3, wherein said description is selected from a group consisting of a netlist representation, a descriptive language representation, and a standard-cell representation of said design-specific cell, wherein said standard-cell is used in an IC design process.
5. (original) The method of claim 1, wherein said design specification is selected from the group consisting of: size (area), signal timing, transistor sizing, number of transistors, power consumption, length of interconnects within said design-specific cell,

output signal strength, input signal impedance, noise characteristics, and a combination thereof.

6. (original) The method of claim 1, wherein said step of mapping comprises: generating a transistor netlist based on at least one netlist generation algorithm; and evaluating said generated transistor netlist based on at least one design specification.

7. (original) The method of claim 1, wherein said step of mapping is based on at least one of a plurality of topology formats.

8. (original) The method of claim 6, wherein said step of mapping further comprises optimizing transistor size for said generated transistor netlist.

9. (original) The method of claim 1, wherein said method further comprises the step of creating at least one transistor-level redundancy for aiding in satisfying said design specification.

10. (original) The method of claim 1, wherein said method further comprises the step of detecting an implementation weakness in a cell for implementing said IC.

11. (currently amended) A system for automatically designing an integrated circuit (IC) design-specific cell, said system comprising:

an interface for receiving a design specification for electrical behavior or transistor-level characteristics of said design-specific cell;

means for mapping a mapping process that maps said design specification to a transistor-level representation of said design-specific cell, wherein said means for mapping uses said design-specific specification as a basis for the mapping; and;

~~means for evaluating~~ an evaluating process that evaluates said transistor-level representation of said design-specific cell for determining whether said transistor-level representation of said IC meets said design specification; and an alteration process that alters said transistor-level representation of said design-specific cell to meet said design specification.

12. (currently amended) The system of claim 11, wherein said ~~means for evaluating~~ is capable of evaluating evaluating process evaluates said transistor-level representation of said design-specific cell based on a specific design context in which said design-specific cell is to be used.

13. (original) The system of claim 11, wherein said interface receives a description of said design-specific cell.

14. (original) The system of claim 13, wherein said description received by said interface is selected from a group consisting of: a netlist representation, a descriptive language representation, and a standard-cell representation of said design-specific cell, wherein said standard-cell is used in an IC design process.

15. (currently amended) The system of claim 11, wherein said ~~means for mapping~~ process controls the mapping of said transistor-level representation on the basis of said ~~design-specific design~~ specification selected from the group consisting of: size (area), signal timing, transistor sizing, number of transistors, power consumption, fault tolerance, integrity characteristics, noise characteristics, and a combination thereof.

16. (currently amended) The system of claim 11, wherein said ~~means for mapping~~ is capable of generating mapping process generates a transistor netlist based on at least one netlist generation algorithm; ~~and evaluating, and evaluates~~ said generated transistor netlist based on at least one design specification.

17. (currently amended) The system of claim 11, wherein said ~~means for mapping process~~ further comprises a ~~control means for~~ controller that controls the mapping using a plurality of topology formats.

18. (currently amended) The system of claim 11, wherein said ~~means for mapping process~~ further comprises a ~~control means~~ controller for optimization of transistor sizing for said generated transistor netlist.

19. (currently amended) The system of claim 11, wherein said system further comprises ~~means for creating a process that creates~~ at least one transistor-level redundancy for said IC cell for aiding in meeting said design specification.

20. (currently amended) The system of claim 11, wherein said system further comprises ~~means for detecting a detector that detects~~ an implementation weakness in a cell for implementing said IC.

21. (currently amended) A design-specific cell produced by an automated integrated circuit (IC) design process, said IC design process comprises the steps of:  
receiving a design specification for electrical behavior or transistor-level characteristics of said design-specific cell;  
mapping said design specification to a transistor-level representation of said design-specific cell; ~~said mapping based on said design specification~~; and  
evaluating said transistor-level representation of said design-specific cell for meeting of said design specification; and  
altering said transistor-level representation of said design-specific cell to meet said design specification.

22. (previously presented) The design-specific cell produced by the IC design process of claim 21, wherein said step of evaluating comprises evaluating said transistor-level representation of said design-specific cell based on a specific design context in which said design-specific cell is to be used.

23. (original) The design-specific cell produced by the IC design process of claim 21, wherein said step of receiving comprises receiving a description of said design-specific cell.

24. (original) The design-specific cell produced by the IC design process of claim 23, wherein said description is selected from a group consisting of: a netlist representation, a descriptive language representation, and a standard-cell representation of said design-specific cell, wherein said standard-cell is used in an IC design process.

25. (original) The design-specific cell produced by the IC design process of claim 21, wherein said design specification is selected from the group consisting of: size (area), signal timing, transistor sizing, number of transistors, power consumption, length of interconnects within said design-specific cell, output signal strength, input signal impedance, noise characteristics, and a combination thereof.

26. (original) The design-specific cell produced by the IC design process of claim 21, wherein said step of mapping comprises:  
generating a transistor netlist based on at least one netlist generation algorithm; and  
evaluating said generated transistor netlist based on at least one design specification.

27. (original) The design-specific cell produced by the IC design process of claim 21, wherein said step of mapping is based on at least one plurality of topology format.

28. (currently amended) The design-specific cell produced by the IC design process of claim ~~21~~ 26, wherein said step of mapping further comprises ~~means for~~ optimizing the transistor size for said generated transistor netlist.

29. (original) The design-specific cell produced by the IC design process of claim 21, wherein said method further comprises the step of creating at least one transistor-level redundancy for aiding in meeting said design specification.

30. (currently amended) A storage medium having computer readable program instructions embodied therein for automatically designing an integrated circuit (IC) design-specific cell, said storage medium comprising:

program instructions for receiving a design specification for electrical behavior or transistor-level characteristics of said design-specific cell;

program instructions for mapping said design specification to a transistor-level representation of said design-specific cell, ~~said mapping based on said design specification; and;~~

program instructions for evaluating said transistor-level representation of said design-specific cell for satisfaction of said design specification; and

program instructions for altering said transistor-level representation of said design-specific cell to meet said design specification.

31. (previously presented) The method of claim 1, wherein said design specification comprises electrical behavior and transistor-level characteristics of said design-specific cell.

32. (previously presented) The system of claim 11, wherein said design specification comprises electrical behavior and transistor-level characteristics of said design-specific cell.

33. (previously presented) The design-specific cell produced by an automated integrated circuit (IC) design process of claim 21, wherein said design specification comprises electrical behavior and transistor-level characteristics of said design-specific cell.

34. (previously presented) The storage medium of claim 30, wherein said design specification comprises electrical behavior and transistor-level characteristics of said design-specific cell.

35. (previously presented) The method of claim 1, wherein said integrated circuit design-specific cell is selected from the group consisting of: CMOS cells, static CMOS cells, dynamic CMOS cells and combinations thereof.

36. (previously presented) The system of claim 11, wherein said integrated circuit design-specific cell is selected from the group consisting of: CMOS cells, static CMOS cells, dynamic CMOS cells and combinations thereof.

37. (previously presented) The design-specific cell of claim 21, wherein the integrated circuit design-specific cell is selected from the group consisting of: CMOS cells, static CMOS cells, dynamic CMOS cells and combinations thereof.

38. (previously presented) The storage medium of claim 30, wherein said integrated circuit design-specific cell is selected from the group consisting of: CMOS cells, static CMOS cells, dynamic CMOS cells and combinations thereof.